

Erratum

All the physical and electrical parameters of the MOS transistor on a single graph ($Q\Psi$)

G. Vincent^a

Département de Physique, Université Joseph Fourier, Grenoble, France
Laboratoire de Technologie de la Microélectronique, 17 avenue des Martyrs, 38054 Grenoble 9, France

Eur. Phys. J. Appl. Phys. **32**, 155 (2005)

Received 11 March 2006
Published online 2006 – © EDP Sciences

In Section Conclusion (p. 158), the first equation should read:

$$I = \mu_n \frac{W}{L} \frac{\varepsilon_{ox}}{e_{ox}} \left[\left(V_G - 2\psi_b - \frac{V_D}{2} \right) V_D - \frac{2}{3} \frac{\sqrt{2\varepsilon_{SC}qN_a}}{\frac{\varepsilon_{ox}}{e_{ox}}} \left\{ (V_D + 2\psi_b + |V_{sub}|)^{\frac{3}{2}} - (2\psi_b + |V_{sub}|)^{\frac{3}{2}} \right\} \right].$$

^a e-mail: gilbert.belledonne@wanadoo.fr